

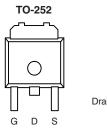
P-Channel 30-V (D-S), MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^a		
- 30	0.010 at V _{GS} = - 10 V	- 15		
	0.018 at V _{GS} = - 4.5 V	- 12		

FEATURES

• TrenchFET[®] Power MOSFETs





Drain Connected to Tab



Top View

Ordering Information: SUD45P03-10-E3 (Lead (Pb)-free)

P-Channel	MOSFET

S

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted						
Parameter		Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	- 30	v		
Gate-Source Voltage		V _{GS}	± 20			
	T _A = 25 °C	1_	- 15	•		
Continuous Drain Current ^b	T _A = 100 °C	I _D	- 8			
Pulsed Drain Current		I _{DM}	- 100	A		
Continuous Source Current (Diode Conduction)		۱ _S	- 15	1		
Mariana Diata tingh	T _C = 25 °C	P_	70	w		
Maximum Power Dissipation ^b	T _A = 25 °C	P _D	4 ^b			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^b	R _{thJA}		30	°C/W	
Maximum Junction-to-Case	R _{thJC}		1.8	0/10	

Notes:

a. Calculated Rating for T_A = 25 °C, for comparison purposes only. This cannot be used as continuous rating (see Absolute Maximum Ratings and Typical Characteristics).

b. Surface Mounted on FR4 board, t \leq 10 s.



SUD45P03-10 P-Channel 30-V (D-S), MOSFET

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static		·		•		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 30			v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0		- 3.0	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zara Cata Valtaga Drain Current		$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 125 °C			- 50	μΑ
	1	V _{DS} = - 5 V, V _{GS} = - 10 V	- 50	- 50		٨
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 20			A
		V _{GS} = - 10 V, I _D = - 15 A			0.010	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = - 10 V, I _D = - 15 A, T _J = 125 °C	°C 0.015		0.015	Ω
		V _{GS} = - 4.5 V, I _D = - 15 A			0.018	1
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 15 A	20			S
Dynamic ^b		· · · ·				
Input Capacitance	C _{iss}			6000		pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$, $V_{DS} = -25 V$, f = 1 MHz		1100		
Reverse Transfer Capacitance	C _{rss}]		700		
Total Gate Charge ^c	Qg			90	150	
Gate-Source Charge ^c	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 45 A		20		nC
Gate-Drain Charge ^c	Q _{gd}			16		
Turn-On Delay Time ^c	t _{d(on)}			15	25	
Rise Time ^c	t _r	V_{DD} = - 15 V, R_L = 0.33 Ω		375	550	- ns
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D}\cong$ - 45 A, V_GEN = - 10 V, R_G = 2.4 Ω		100	200	
Fall Time ^c	t _f] [140	250	
Source-Drain Diode Ratings and Cha	racteristic T	_C = 25 °C				
Pulsed Current	I _{SM}				100	А
Diode Forward Voltage ^a	V _{SD}	I _F = - 45 A, V _{GS} = 0 V		1.0	1.5	V
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 45 A, dl/dt = 100 A/μs		55	100	ns

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

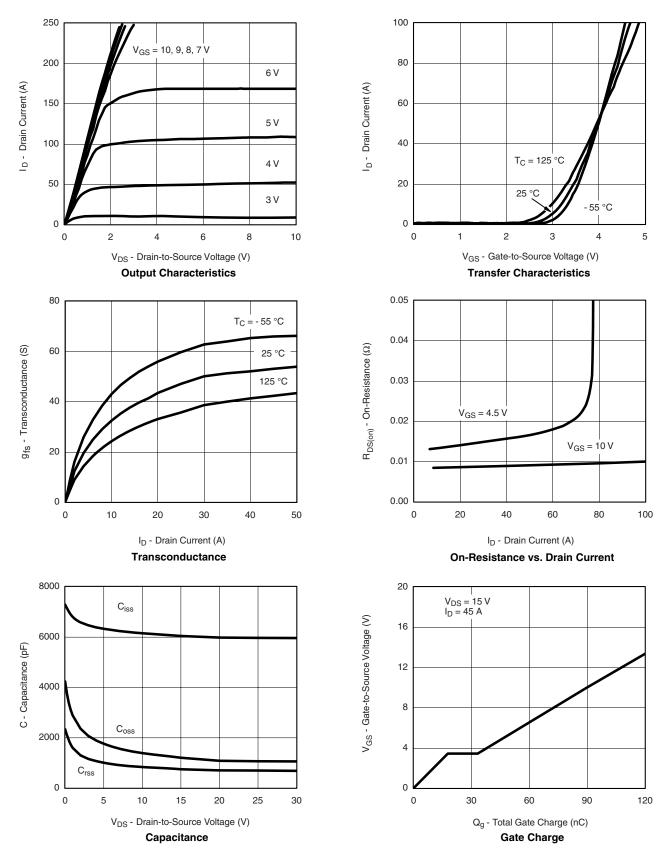
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SUD45P03-10 P-Channel 30-V (D-S), MOSFET

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





SUD45P03-10 P-Channel 30-V (D-S), MOSFET

T_J = 150 °C

0.6

0.9

V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

 $T_J = 25 °\dot{C}$

1.2

1.5

100

10

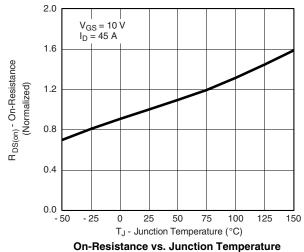
1

0

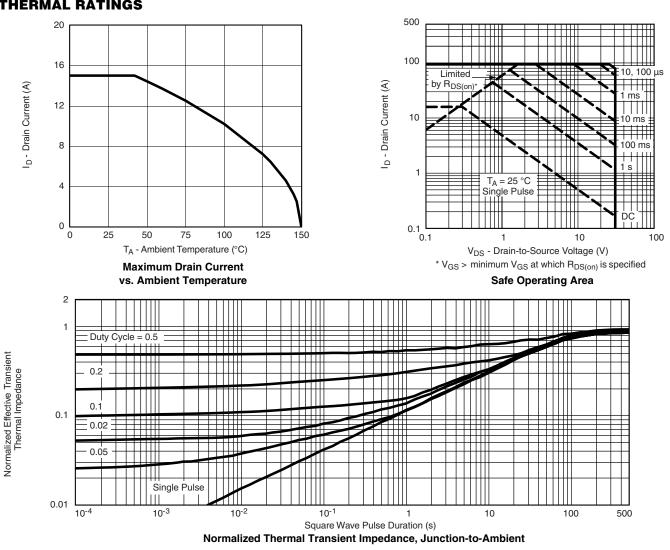
0.3

I_S - Source Current (A)

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



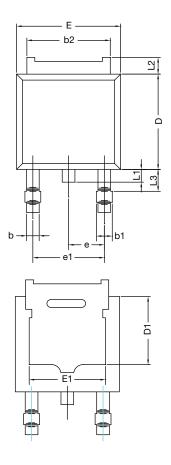


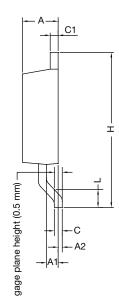




P-Channel 30-V (D-S), MOSFET

TO-252AA CASE OUTLINE





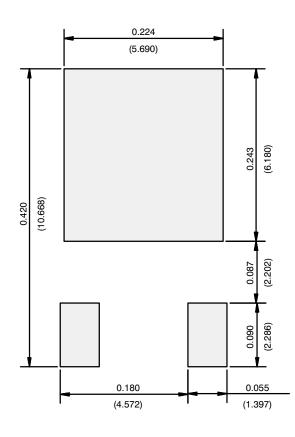
	MILLIN	IETERS	INCHES			
DIM.	MIN.	MAX.	MIN.	MAX.		
А	2.21	2.38	0.087	0.094		
A1	0.89	1.14	0.035	0.045		
A2	0.030	0.127	0.001	0.005		
b	0.71	0.88	0.028	0.035		
b1	0.76	1.14	0.030	0.045		
b2	5.23	5.44	0.206	0.214		
С	0.46	0.58	0.018	0.023		
C1	0.46	0.58	0.018	0.023		
D	5.97	6.22	0.235	0.245		
D1	4.10	4.45	0.161	0.175		
E	6.48	6.73	0.255	0.265		
E1	4.49	5.50	0.177	0.217		
е	2.28	2.28 BSC 0.090 BSC		BSC		
e1	4.57	BSC	0.180	BSC		
Н	9.65	10.41	0.380	0.410		
L	1.40	1.78	0.055	0.070		
L1	0.64	1.02	0.025	0.040		
L2	0.89	1.27	0.035	0.050		
L3	1.15	1.52	0.040	0.060		
ECN: T11-0110-Rev. L, 18-Apr-11 DWG: 5347						

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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